NSN 5961-00-627-1923

Demilitarization:

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-627-1923 **Inclosure Material:** Metal **Overall Length:** Between 0.140 inches and 0.230 inches Overall Diameter: Between 0.240 inches and 0.380 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, emitter-to-base, collector open and 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**